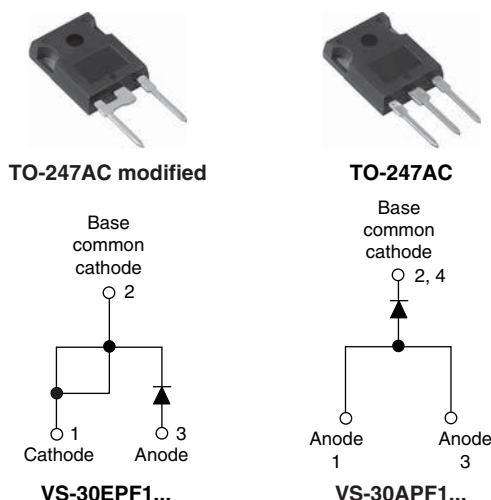


Fast Soft Recovery Rectifier Diode, 30 A



FEATURES

- 150 °C max. operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC-JESD47
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)



RoHS
COMPLIANT
HALOGEN
FREE
Available

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-30EPF1... and VS-30APF1... soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

PRODUCT SUMMARY

Package	TO-247AC, TO-247AC modified (2 pins)
$I_{F(AV)}$	30 A
V_R	1000 V, 1200 V
V_F at I_F	1.41 V
I_{FSM}	350 A
t_{rr}	95 ns
T_J max.	150 °C
Diode variation	Single die
Snap factor	0.6

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	30	A
V_{RRM}		1000 to 1200	V
I_{FSM}		350	A
V_F	30 A, $T_J = 25$ °C	1.41	V
t_{rr}	1 A, 100 A/μs	95	ns
T_J		- 40 to 150	°C

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
VS-30EPF10PbF, VS-30APF10PbF VS-30EPF10-M3, VS-30APF10-M3	1000	1100	6
VS-30EPF12PbF, VS-30APF12PbF VS-30EPF12-M3, VS-30APF12-M3	1200	1300	

**ABSOLUTE MAXIMUM RATINGS**

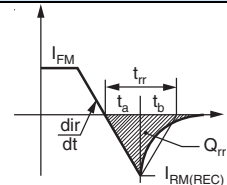
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 95\text{ }^{\circ}\text{C}$, 180° conduction half sine wave	30	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	300	
		10 ms sine pulse, no voltage reapplied	350	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	450	A^2s
		10 ms sine pulse, no voltage reapplied	636	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to }10\text{ ms}$, no voltage reapplied	6360	$\text{A}^2\sqrt{\text{s}}$

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	30 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.41	V
Forward slope resistance	r_t	$T_J = 150\text{ }^{\circ}\text{C}$	10.09	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$		0.992	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^{\circ}\text{C}$	0.1	mA
		$T_J = 150\text{ }^{\circ}\text{C}$	6	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 30 A _{pk} 25 A/ μs 25 °C	450	ns
Reverse recovery current	I_{rr}		6.1	A
Reverse recovery charge	Q_{rr}		2.16	μC
Snap factor	S	Typical	0.6	

**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.8	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		40	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AC modified	30EPF10	
			30EPF12	
		Case style TO-247AC	30APF10	
			30APF12	

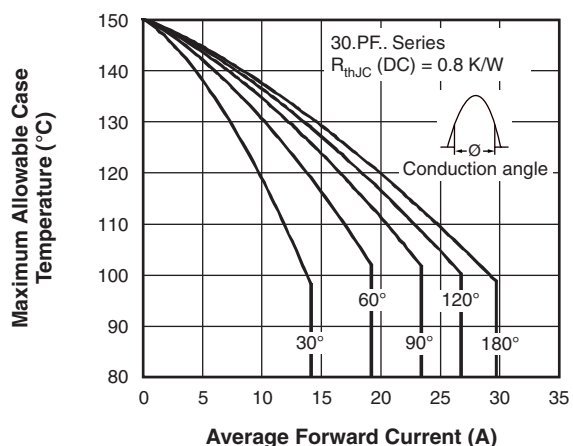


Fig. 1 - Current Rating Characteristics

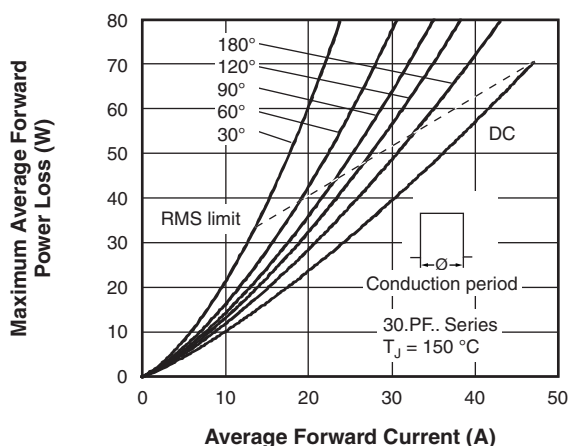


Fig. 4 - Forward Power Loss Characteristics

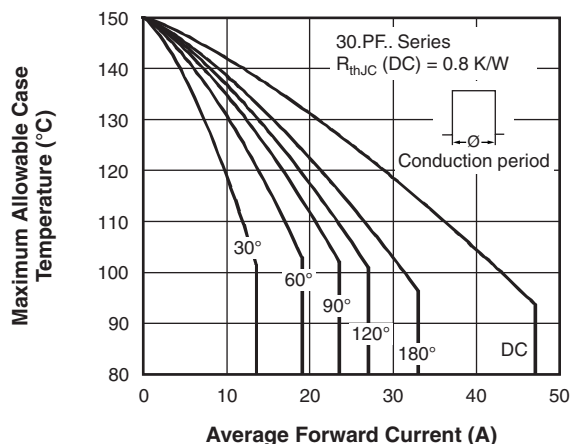


Fig. 2 - Current Rating Characteristics

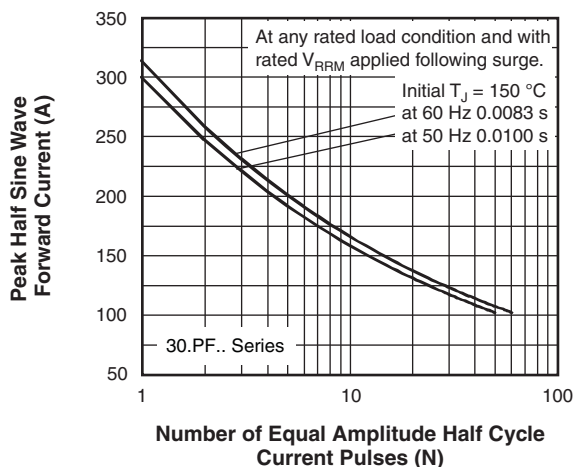


Fig. 5 - Maximum Non-Repetitive Surge Current

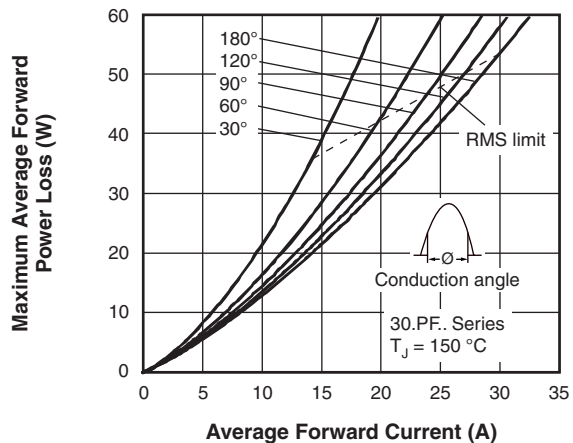


Fig. 3 - Forward Power Loss Characteristics

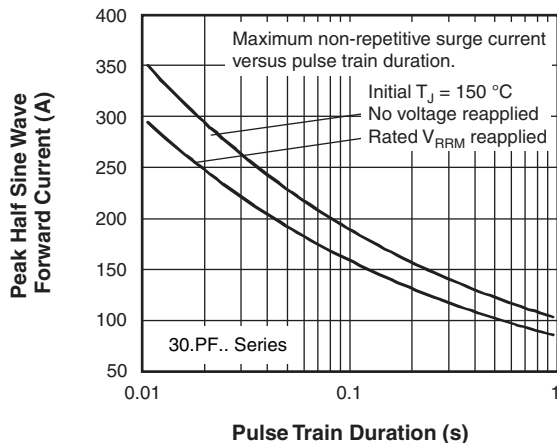


Fig. 6 - Maximum Non-Repetitive Surge Current

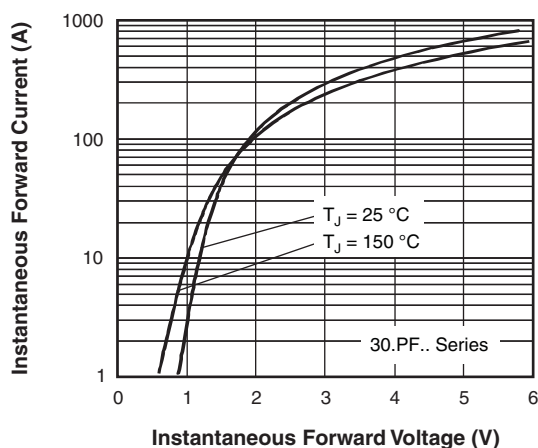


Fig. 7 - Forward Voltage Drop Characteristics

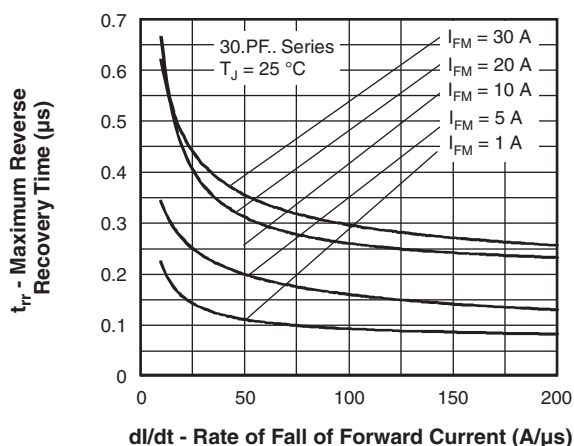


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

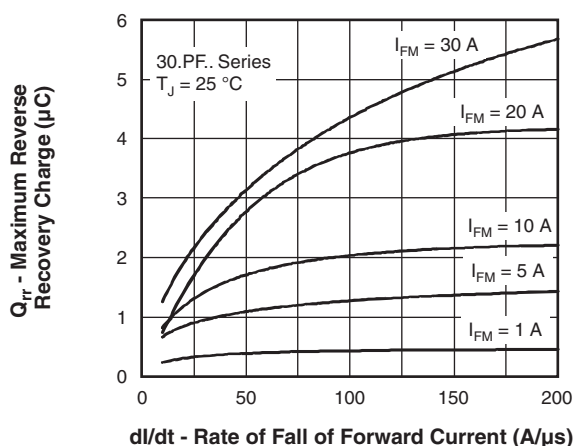


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

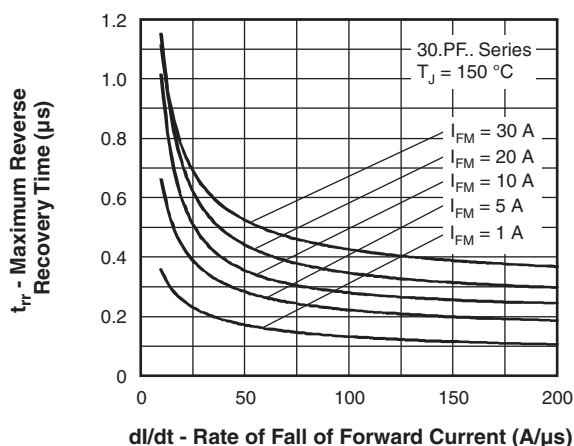


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

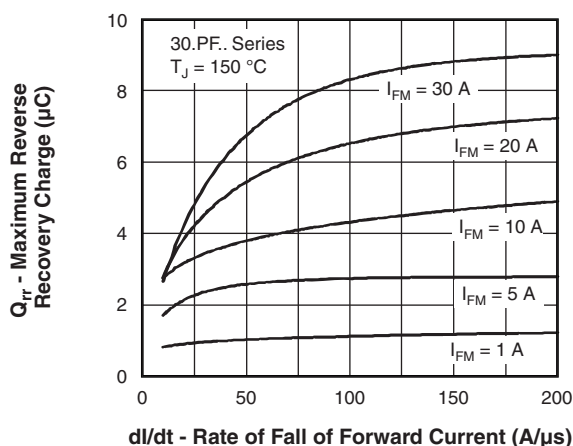


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

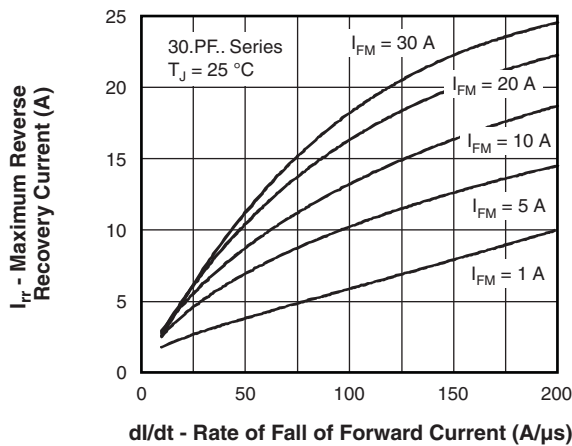


Fig. 12 - Recovery Current Characteristics, $T_J = 25^\circ C$

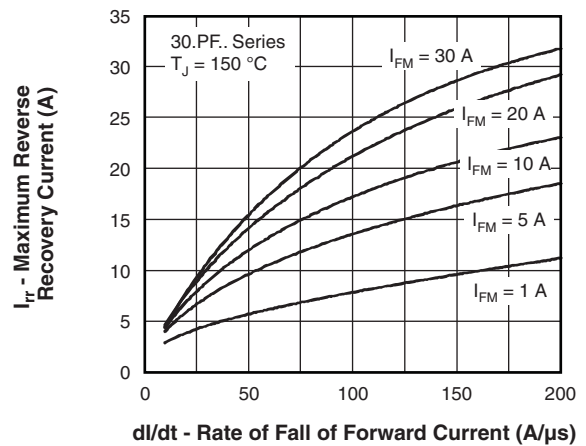


Fig. 13 - Recovery Current Characteristics, $T_J = 150^\circ C$

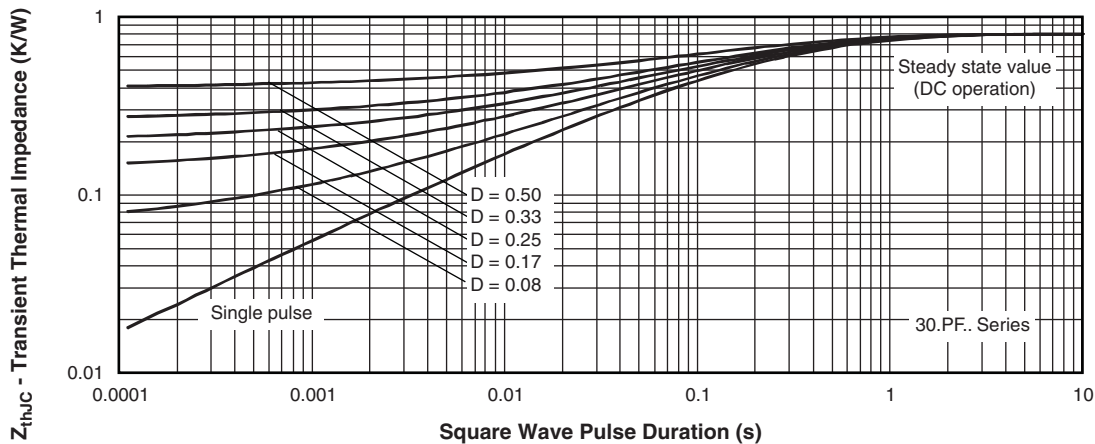


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

**ORDERING INFORMATION TABLE**

Device code	VS-	30	E	P	F	12	PbF
	1	2	3	4	5	6	7
1	Vishay Semiconductors product						
2	Current rating (30 = 30 A)						
3	Circuit configuration: E = Single diode A = Single diode, 3 pins						
4	Package: P = TO-247AC/TO-247AC modified						
5	Type of silicon: F = Fast recovery						
6	Voltage code x 100 = V_{RRM}						
7	Environmental digit:						
	• PbF = Lead (Pb)-free and RoHS compliant						
	• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free						

10 = 1000 V
12 = 1200 V

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-30EPF10PbF	25	500	Antistatic plastic tubes
VS-30EPF10-M3	25	500	Antistatic plastic tubes
VS-30APF10PbF	25	500	Antistatic plastic tubes
VS-30APF10-M3	25	500	Antistatic plastic tubes
VS-30EPF12PbF	25	500	Antistatic plastic tubes
VS-30EPF12-M3	25	500	Antistatic plastic tubes
VS-30APF12PbF	25	500	Antistatic plastic tubes
VS-30APF12-M3	25	500	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-247AC modified	www.vishay.com/doc?95253
	TO-247AC	www.vishay.com/doc?95223
Part marking information	TO-247AC modified PbF	www.vishay.com/doc?95255
	TO-247AC modified -M3	www.vishay.com/doc?95442
	TO-247AC PbF	www.vishay.com/doc?95226
	TO-247AC -M3	www.vishay.com/doc?95007
SPIICE model		www.vishay.com/doc?95184



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<http://moschip.ru/get-element>

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